

CERTIFICATE OF TRANSMISSION BY FACSIMILE (37 CFR 1.8)

Applicant(s): Lu et al.

Docket No.

YO998532

Serial No.

09/296,588

Filing Date

April 23, 1999

Examiner

Qi, Lang

Group Art Unit

2871

Invention: **METHODS OF REDUCING UNBALANCED DC VOLTAGE BETWEEN TWO ELECTRODES OF REFLECTIVE LIQUID CRYSTAL DISPLAY BY THIN FILM PASSIVATION**

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Second Supplemental Amendment Under 37 C.F.R. 1.111

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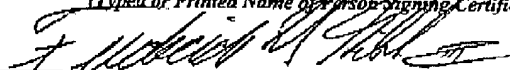
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In re patent application of

Lu et al.

Serial No. 09/296,588

Group Art Unit: 2871

Filed: April 23, 1999

Examiner: Qi. Lang

For: METHODS OF REDUCING UNBALANCED DC VOLTAGE
BETWEEN TWO ELECTRODES OF REFLECTIVE LIQUID
CRYSTAL DISPLAY BY THIN FILM PASSIVATION

Commissioner of Patents
P.O. Box 1450
Alexandria, VA 22313-1450

SECOND SUPPLEMENTAL AMENDMENT UNDER 37 C.F.R. §1.111

Sir:

In further response to the Office Action mailed February 25, 2003 and further to the Amendments filed by Applicants on May 22, 2003 and July 1, 2003, Applicant's hereby submit a clean copy of all claims in response to the Examiner's telephonic request.

IN THE CLAIMS:

1. (Previously Presented) A reflective-type liquid crystal display comprising:
a first-type electrode;
a second-type electrode positioned opposite said first-type electrode and being of an opposite type than said first-type electrode; and
a liquid crystal material between said first-type electrode and said second-type electrode,
wherein at least one of said first-type electrode and said second-type electrode includes a conducting amorphous layer adjacent said liquid crystal material, wherein said conducting amorphous layer has a resistivity between 10^4 and 10^{11} ohms-cm.